



BTB04-600SL

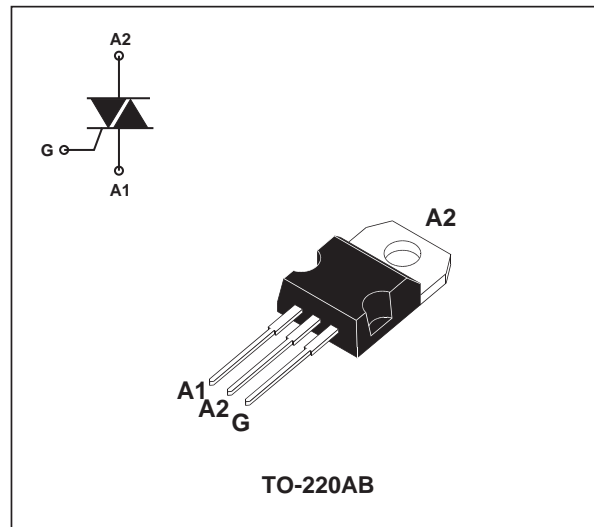
STANDARD 4A TRIAC

MAIN FEATURES

Symbol	Value	Unit
$I_{T(RMS)}$	4	A
V_{DRM} / V_{RRM}	600	V
$I_{GT(Q1)}$	10	mA

DESCRIPTION

The BTB04-600SL 4 quadrants TRIAC is intended for general purpose applications where high surge current capability is required, such as lighting, corded power tools, industrial. This TRIAC features a gate current capability sensitivity of 10mA.



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
$I_{T(RMS)}$	RMS on-state current (full sine wave)	TO-220AB $T_c = 105^{\circ}\text{C}$	4 A
I_{TSM}	Non repetitive surge peak on-state current (full cycle, T_j initial = 25°C)	$F = 50\text{ Hz}$ $t = 20\text{ ms}$	35 A
		$F = 60\text{ Hz}$ $t = 16.7\text{ ms}$	38 A
I^2t	I^2t value for fusing	$t_p = 10\text{ms}$	6 A^2s
di/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, $t_r \leq 100\text{ ns}$	Repetitive $F = 100\text{Hz}$	50 $\text{A}/\mu\text{s}$
I_{GM}	Peak gate	$t_p = 20\mu\text{s}$ $T_j = 125^{\circ}\text{C}$	4 A
$P_{G(AV)}$	Average gate power dissipation	$T_j = 125^{\circ}\text{C}$	0.5 W
T_{stg}	Storage junction temperature range		-40 to +150 $^{\circ}\text{C}$
T_j	Operating junction temperature range		-40 to +125 $^{\circ}\text{C}$

BTB04-600SL

ELECTRICAL CHARACTERISTICS (T_j = 25°C, unless otherwise specified)

Symbol	Test conditions	Quadrant		Value	Unit
I _{GT} ⁽¹⁾	V _D = 12V R _L = 30Ω	I - II - III	MAX.	10	mA
		IV	MAX.	25	
V _{GT}	V _D = 12V R _L = 30Ω	ALL	MAX.	1.3	V
V _{GD}	V _D = V _{DRM} R _L = 3.3kΩ T _j = 125°C	ALL	MIN.	0.2	V
I _H ⁽²⁾	I _T = 100mA		MAX.	15	mA
I _L	I _G = 1.2I _{GT}	I - III - IV	MAX.	15	mA
		II		25	
dV/dt ⁽²⁾	V _D = 67% V _{DRM} gate open T _j = 125°C		MIN.	75	V/μs
(dV/dt) _c ⁽²⁾	(dI/dt) _c = 1.8A/ms T _j = 125°C		MIN.	10	V/μs

STATIC CHARACTERISTICS

Symbol	Test Conditions			Value	Unit
V _{TM} ⁽²⁾	I _{TM} = 5A t _p = 380μs	T _j = 25°C	MAX.	1.5	V
V _{TO} ⁽²⁾	Threshold voltage	T _j = 125°C	MAX.	0.85	V
R _d ⁽²⁾	Dynamic resistance	T _j = 125°C	MAX.	100	mΩ
I _{DRM} I _{RDM}	V _{DRM} = V _{RRM}	T _j = 25°C	MAX.	5	μA
		T _j = 125°C		1	mA

Note 1: minimum I_{GT} is guaranteed at 5% of I_{GT} max.

Note 2: for both polarities of A2 referenced to A1.

THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
R _{th} (j-c)	Junction to case (AC)	3	°C/W
R _{th} (j-a)	Junction to ambient	60	°C/W

PRODUCT SELECTOR

Part Number	Voltage	Sensitivity	Type	Package
BTB04-600SL	600V	10 mA	Standard	TO-220AB

ORDERING INFORMATION

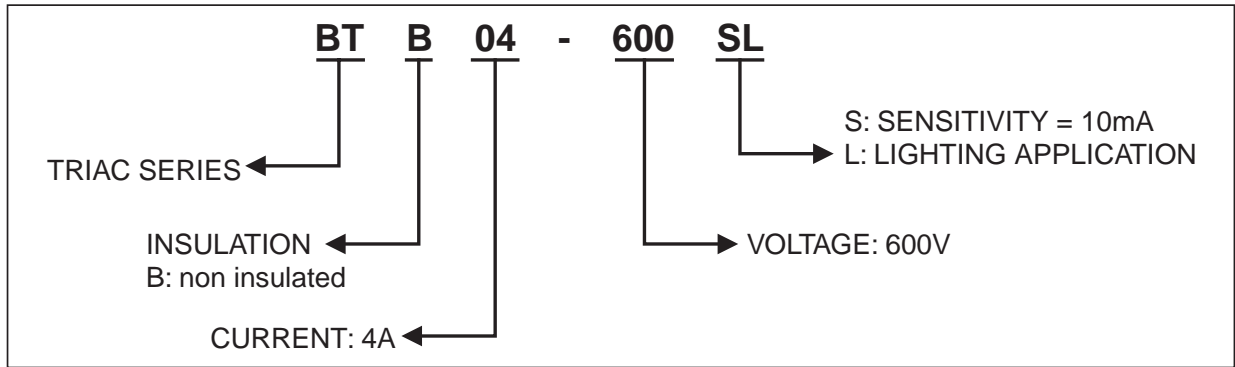


Fig. 1: Maximum power dissipation versus RMS on-state current

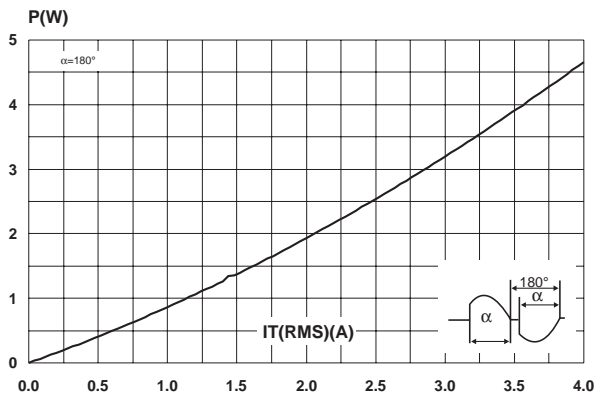


Fig. 3: Relative variation of thermal impedance versus pulse duration.

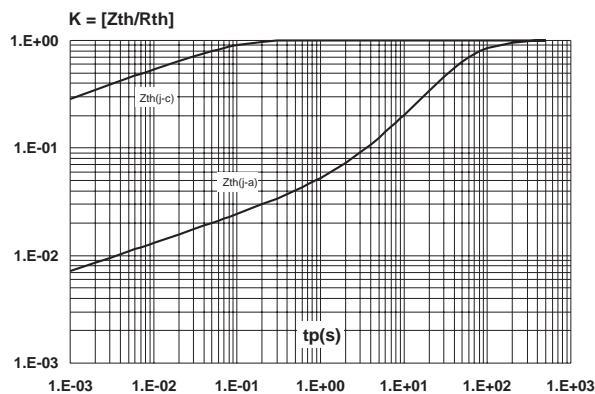


Fig. 2: RMS on-state current versus case temperature.

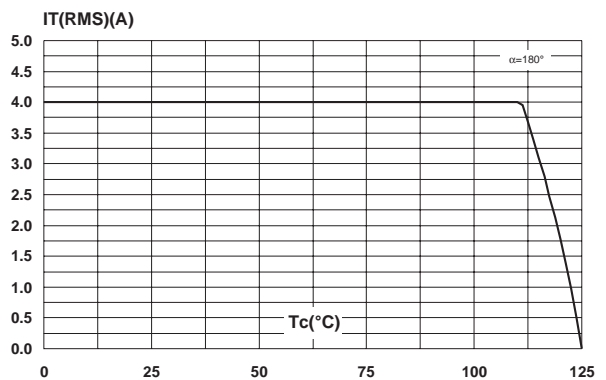


Fig. 4: On-state characteristics (maximum values)

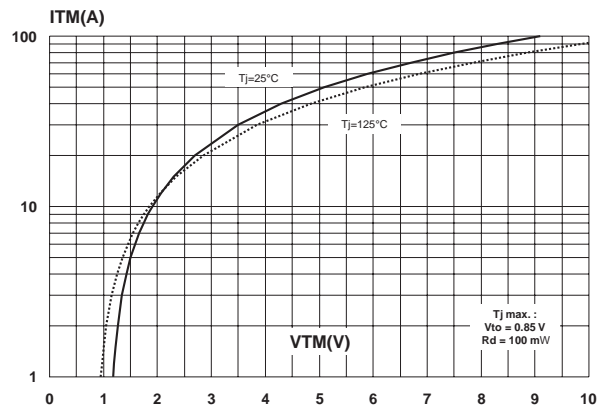


Fig. 5: Surge peak on-state current versus number of cycles.

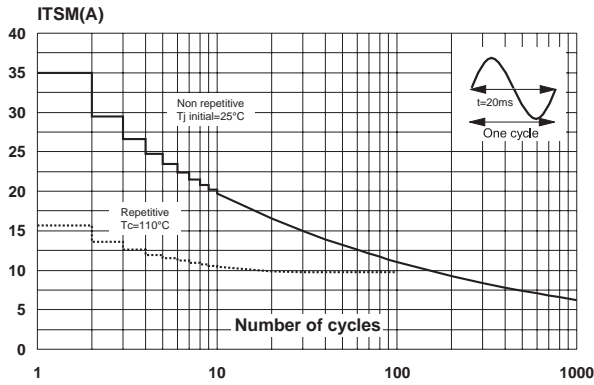


Fig. 6: Non repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10\text{ms}$, and corresponding value of I^2t .

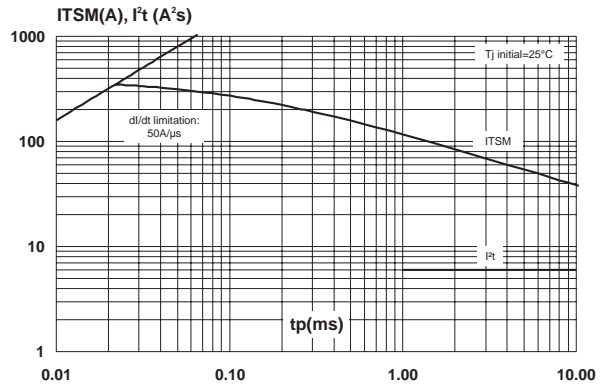


Fig. 7: Relative variation of gate trigger current, holding current and latching current versus junction temperature (typical values).

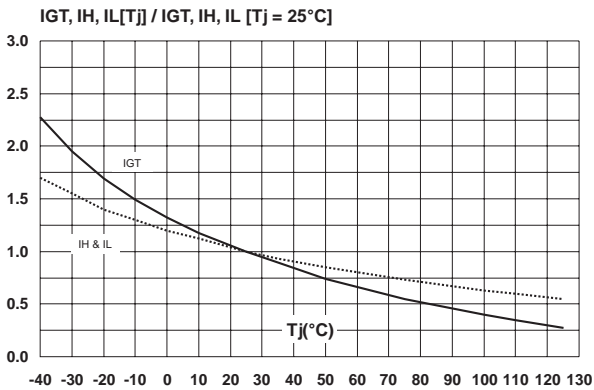


Fig. 8: Relative variation of critical rate of decrease of main current versus reapplied dV/dt (typical values).

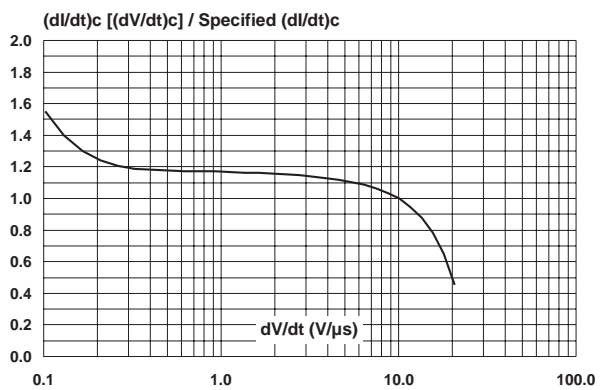


Fig. 9: Relative variation of critical rate of decrease of main current versus junction temperature.

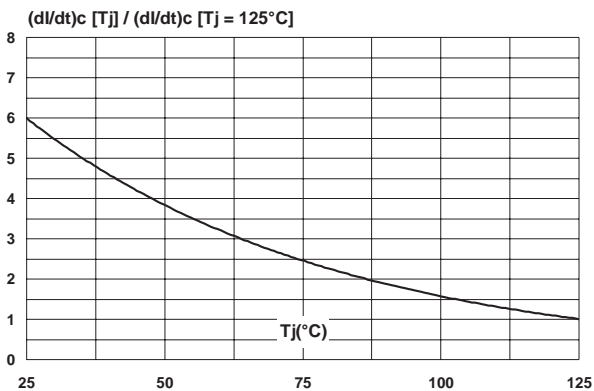
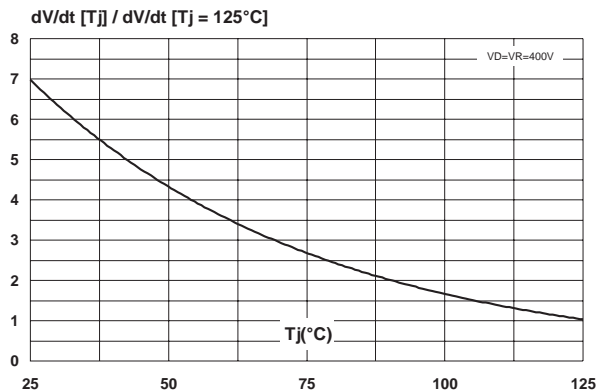


Fig. 10: Relative variation of static dV/dt immunity versus junction temperature.



PACKAGE MECHANICAL DATA
 TO-220AB (Plastic)

REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
C	1.23	1.32	0.048	0.051
D	2.40	2.72	0.094	0.107
E	0.49	0.70	0.019	0.027
F	0.61	0.88	0.024	0.034
F1	1.14	1.70	0.044	0.066
F2	1.14	1.70	0.044	0.066
G	4.95	5.15	0.194	0.202
G1	2.40	2.70	0.094	0.106
H2	10	10.40	0.393	0.409
L2	16.4 typ.		0.645 typ.	
L4	13	14	0.511	0.551
L5	2.65	2.95	0.104	0.116
L6	15.25	15.75	0.600	0.620
L7	6.20	6.60	0.244	0.259
L9	3.50	3.93	0.137	0.154
M	2.6 typ.		0.102 typ.	
Diam.	3.75	3.85	0.147	0.151

OTHER INFORMATION

Ordering type	Marking	Package	Weight	Base qty	Packing mode
BTB04-600SL	BTB04-600SL	TO-220AB	2.3 g	50	Tube

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